

TOSHIBA TRANSISTOR SILICON NPN TRIPLE DIFFUSED TYPE

# 2SC3306

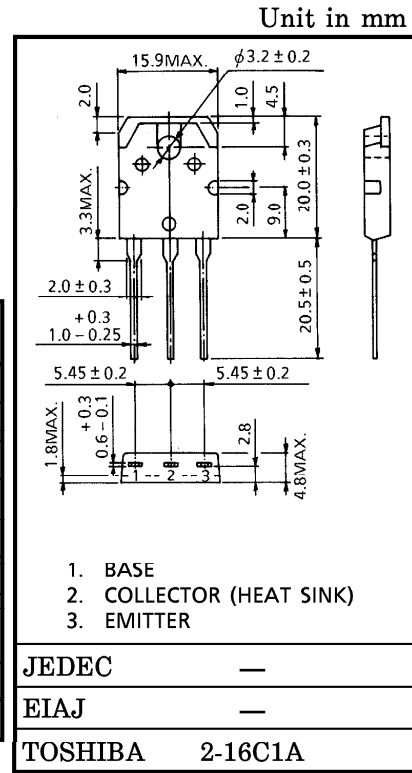
SWITCHING REGULATOR AND HIGH VOLTAGE SWITCHING APPLICATIONS.

HIGH SPEED DC-DC CONVERTER APPLICATIONS.

- Excellent Switching Times  
:  $t_r = 1.0\mu s$  (Max.),  $t_f = 1.0\mu s$  (Max.) ( $I_C = 5A$ )
- High Collector Breakdown Voltage :  $V_{CEO} = 400V$

MAXIMUM RATINGS ( $T_a = 25^\circ C$ )

CHARACTERISTIC		SYMBOL	RATING	UNIT
Collector-Base Voltage		$V_{CBO}$	500	V
Collector-Emitter Voltage		$V_{CEO}$	400	V
Emitter-Base Voltage		$V_{EBO}$	7	V
Collector Current	DC	$I_C$	10	A
	Pulse	$I_{CP}$	15	
Base Current		$I_B$	5	A
Collector Power Dissipation ( $T_c = 25^\circ C$ )		$P_C$	100	W
Junction Temperature		$T_j$	150	$^\circ C$
Storage Temperature Range		$T_{stg}$	-55~150	$^\circ C$



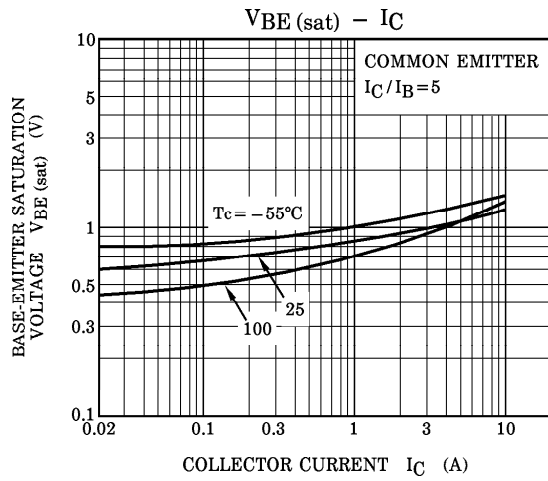
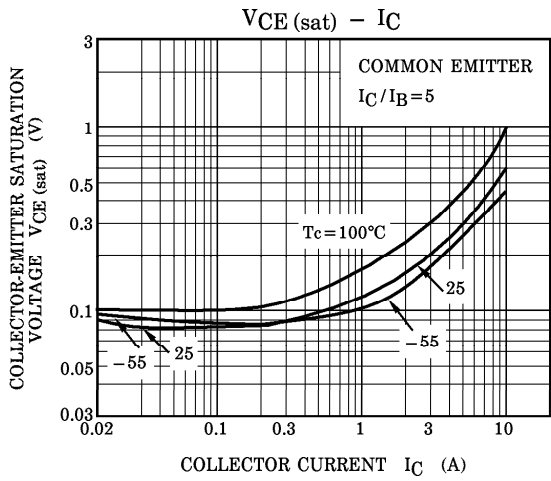
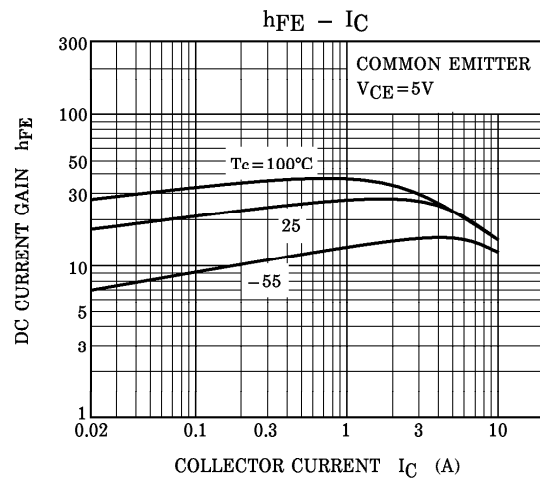
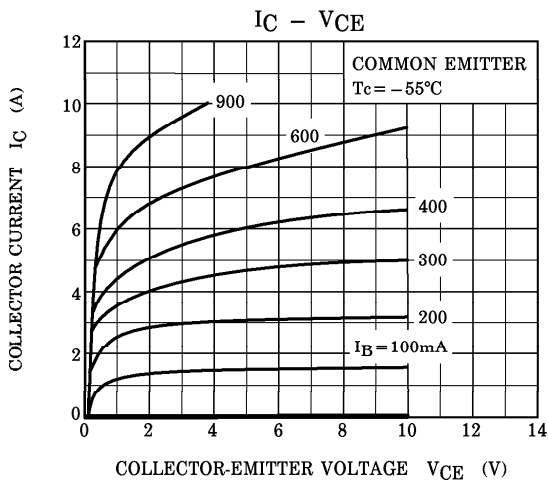
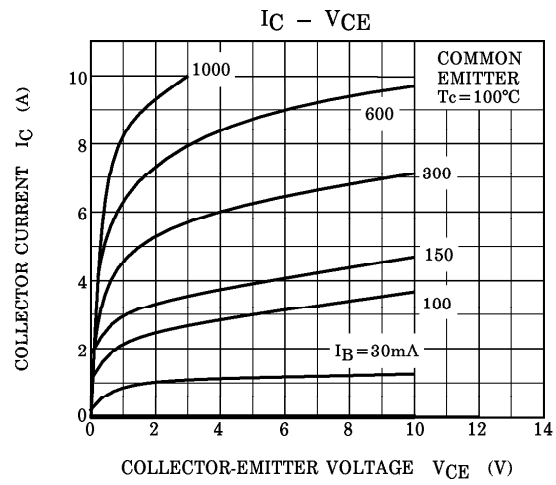
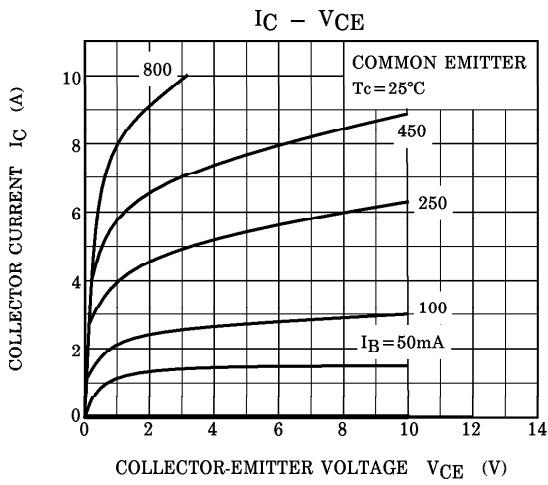
Weight : 4.7g

ELECTRICAL CHARACTERISTICS ( $T_a = 25^\circ C$ )

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current		$I_{CBO}$	$V_{CB} = 400V, I_E = 0$	—	—	100	$\mu A$
Emitter Cut-off Current		$I_{EBO}$	$V_{EB} = 7V, I_C = 0$	—	—	1	mA
Collector-Base Breakdown Voltage		$V_{(BR)CBO}$	$I_C = 1mA, I_E = 0$	500	—	—	V
Collector-Emitter Breakdown Voltage		$V_{(BR)CEO}$	$I_C = 10mA, I_B = 0$	400	—	—	V
DC Current Gain		$h_{FE}$	$V_C = 5V, I_C = 5A$	10	—	—	
Collector-Emitter Saturation Voltage		$V_{CE(sat)}$	$I_C = 5A, I_B = 0.5A$	—	—	1.5	V
Base-Emitter Saturation Voltage		$V_{BE(sat)}$	$I_C = 5A, I_B = 0.5A$	—	—	2.0	V
Switching Time	Rise Time	$t_r$	<p><math>I_{B1} = 20\mu s</math> <math>V_{CC} = 200V</math> <math>I_C = 5A</math> <math>I_B = 0.5A</math> INPUT OUTPUT</p>	—	—	1.0	$\mu s$
	Storage Time	$t_{stg}$		—	—	2.5	
	Fall Time	$t_f$		$I_{B1} = -I_{B2} = 0.5A$ DUTY CYCLE $\leq 1\%$	—	—	

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